

**isc N-Channel MOSFET Transistor**
**FDP120N10**
**• FEATURES**

- With TO-220 packaging
- Drain Source Voltage-  
:  $V_{DSS} \geq 100V$
- Static drain-source on-resistance:  
 $R_{DS(on)} \leq 12m\Omega @ V_{GS}=10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• APPLICATIONS**

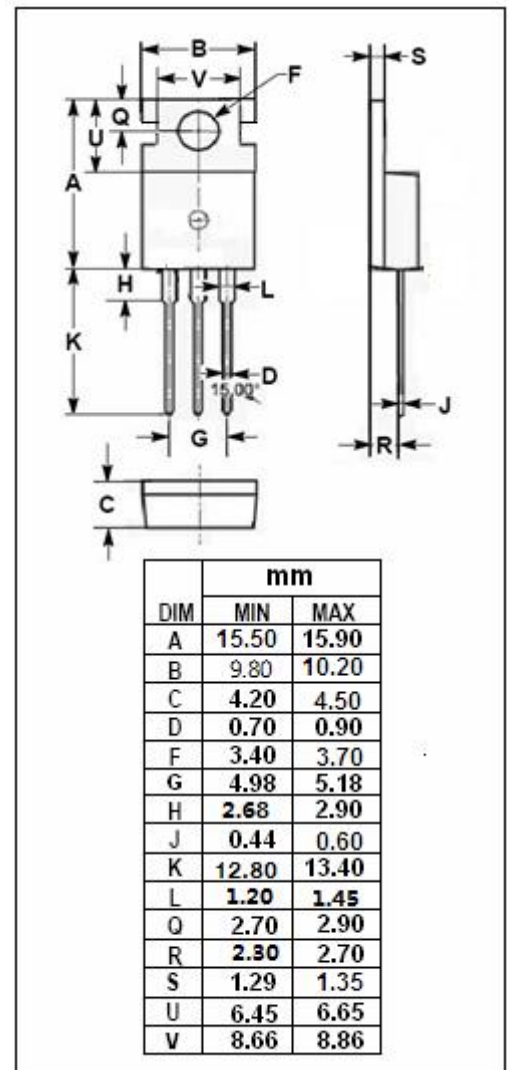
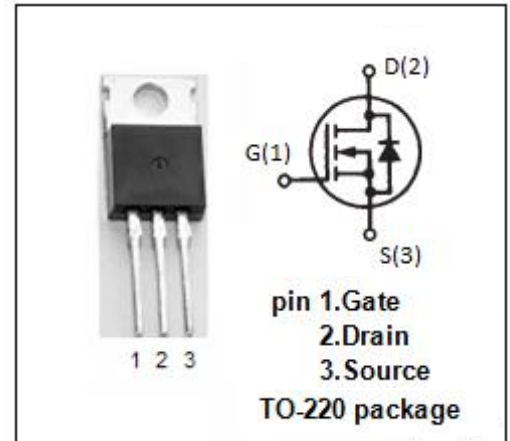
- Power supply
- Switching applications

**• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	100	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous;@ $T_c=25^\circ C$	74	A
$I_{DM}$	Drain Current-Single Pulsed	296	A
$P_D$	Total Dissipation	170	W
$T_j$	Operating Junction Temperature	-55~175	$^\circ C$
$T_{stg}$	Storage Temperature	-55~175	$^\circ C$

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.88	$^\circ C/W$



## isc N-Channel MOSFET Transistor

## FDP120N10

## ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250uA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250uA	2.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 74A			12	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V; V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V; T <sub>J</sub> =150°C			1 500	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> = 74A, V <sub>GS</sub> = 0 V			1.3	V

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